

AC evidence of a field tuned 2D superconductor-metal transition in a low-disorder InO_x film

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Employing microwave spectroscopy, we investigated the field tuned quantum phase transition between the superconducting and the resistive states in a low-disorder amorphous InO_x film in the frequency range of 0.05 to 16 GHz. Our AC measurements are explicitly sensitive to the critical slowing down of the characteristic frequency scales approaching a transition. The relevant frequency scale of superconducting fluctuations approaches zero at a field B_{sm} far below the field B_{cross} where different isotherms of resistance as a function of magnetic field cross each other. The phase stiffness at the lowest frequency vanishes from the superconducting side at $B \approx B_{sm}$, while the high frequency limit extrapolates to zero near B_{cross} . Our data are consistent with a scenario where B_{sm} is the true quantum critical point for a transition from a superconductor to an anomalous metal, while B_{cross} only signifies a crossover to a regime where superconducting correlations make a vanishing contribution to both AC and DC transport measurements in the low-disorder limit.

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A quantum phase transition (QPT) is a zero temperature change of state as a function of a non-thermal parameter. The two dimensional (2D) superconductor-insulator transition (SIT) is an emblematic example of a QPT and has been the subject of many theoretical and experimental studies [1, 2]. As conventionally envisioned, superconductivity can be suppressed by applying magnetic fields beyond some critical value whereupon the system transitions to an insulating state with a diverging resistance at $T = 0$. One possible scenario is that this transition occurs via a “fermionic” mechanism by destroying the amplitude of the superconducting order parameter. At the transition point, superconducting correlations are strongly suppressed. Another possibility is a “bosonic” mechanism in which the Cooper pairs become localized through quantum disordering of the order parameter’s phase. In this case, one expects pairing to exist on both sides of the transition.

Within the latter bosonic description, a universal resistance of order the quantum resistance for Cooper pairs $R_Q = h/4e^2 \approx 6450 \Omega$ is expected at the quantum critical point (QCP) [1]. Although some indications for superconducting correlations in the insulating state have been reported [3–5], there has been little definitive evidence in favor of this pure bosonic model. Some systems do exhibit a resistance of order R_Q at the transition; however, others show a much smaller critical resistance [6]. Moreover, instead of a direct transition to an insulator many materials appear to exhibit an intervening metallic region that features a small yet finite saturated resistance at the lowest measured temperatures [7–12]. This effect is usually more pronounced in low-disorder films. In these cases the transition appears to be one from a superconductor to a strange metal with superconducting correlations. A true metallic phase as such may be

surprising because one might naively expect that delocalized bosons would ultimately condense at the lowest temperatures. The physics is still unclear despite various theoretical efforts to demonstrate the possibility of a zero-temperature dissipative state with superconducting correlations [13–17]. On the experimental side, the possibility exists that the apparent zero-temperature DC dissipation could be a consequence of insufficient cooling of the carriers despite careful experimental checks. For these reasons, it is important to utilize experimental probes other than DC transport to investigate this problem.

Microwave spectroscopy gives an advantage in studying the 2D SIT in that one can be explicitly sensitive to temporal correlations. AC measurements provide detailed information about the critical slowing down of the characteristic frequency scales approaching a transition, which may reveal the true location of the QCP. Furthermore, we can study the dynamics of the possible intervening metallic state. Through the imaginary conductance, AC measurements of superconductors also allow access to the phase stiffness $T_\theta(\omega)$, which is directly related to the phase coherence on a length scale set by the probing frequency.

In this Letter, we present novel measurements of the frequency, temperature and field dependence of the complex microwave conductance on a particularly low-disorder superconducting InO_x film through its QPT. From the simultaneously measured DC resistance, a well-defined field B_{cross} is identified as the crossing point of different isotherms $R(B)$. In most interpretations of similar data, B_{cross} is taken to be the location of the QCP. However, quite contrary to expectations for the slowing down of fluctuations near the presumed continuous transition at B_{cross} , the relevant frequency scales extrapolate

to zero at a much smaller field B_{sm} . The phase stiffness T_θ at the lowest frequency vanishes from the superconducting side at $B \approx B_{sm}$, while the high frequency limit approaches zero at $B \approx B_{cross}$. Our data support a scenario in which B_{sm} is the true QCP for a transition from a superconductor to an anomalous metal, while B_{cross} only signifies a crossover to a regime where superconducting correlations are strongly suppressed.

Samples are morphologically homogeneous InO_x films prepared by e-gun evaporation of In_2O_3 to a thickness of approximately 30 nm onto high-resistivity Si substrates as described elsewhere [3, 4]. The nominal 2D SIT in InO_x can be tuned by applying perpendicular magnetic fields [3, 4, 18, 19]. Broadband microwave experiments were performed in a home-built Corbino microwave spectrometer coupled into a He-3 cryostat. We measured the complex reflectivity of the sample in the microwave regime, from which complex impedance and conductance can be obtained. Three calibration samples with known reflection coefficients (20nm NiCr on Si, a blank high-resistivity Si substrate and a bulk copper sample) were measured to remove the contributions from the coaxial cables to the reflected signals [20–24]. Two terminal DC resistance can be simultaneously measured *via* a bias tee. The DC resistance without the microwave illuminations was used to carefully check and correct for any microwave induced heating [25]. Calibrations were performed at each displayed magnetic field unless otherwise specified. With substrate corrections [26], the true response of the InO_x film can be isolated at all fields and temperatures.

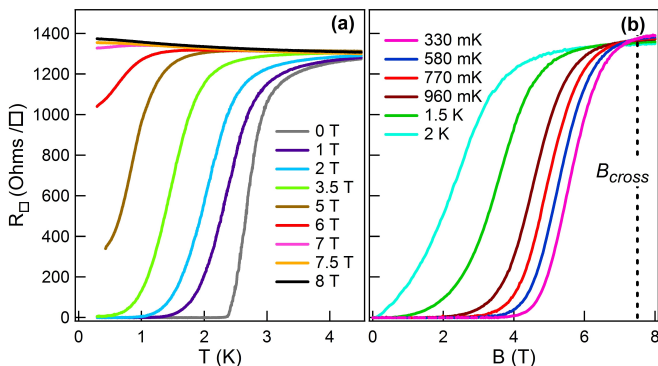


FIG. 1: (Color online) (a) Temperature dependence of sheet resistance $R_\square$ at different fields as indicated by the color legend. (b) $R_\square$ as a function of field at 6 fixed temperatures as shown by the color legend. The crossing point of the two lowest temperature isotherms is approximately 7.5 Tesla.

In Fig. 1 (a) we plot the two-terminal sheet resistance $R_\square$ as a function of temperature at fixed magnetic fields. The particular InO_x film in this paper shows a transition to a zero resistance state at $T_c = 2.36$ K at zero field. Previous microwave studies have demonstrated that its zero-field thermal fluctuations are consistent with a 2D

Kosterlitz-Thouless-Berezinskii transition [24]. The normal state resistance per square R_N is about 1200 Ω . This number is far below R_Q and is comparable to R_N for thin films like $a\text{-MoGe}$ [6]. It implies that this film has a much lower disorder level ($k_F l$ is in the range $3 \sim 6$ [27]) compared to the InO_x films used in many previous QPT studies and falls into the same class of lower-disorder thin films superconductors such as $a\text{-MoGe}$ [16]. At low temperatures, the slopes of the resistance curves change sign at about 7.5 Tesla (see Fig. 1 (a)). For the two lowest temperatures, the data also exhibit an isoresistance crossing point B_{cross} at 7.5 Tesla. This field is conventionally interpreted as the location of QCP. Like $a\text{-MoGe}$, this sample exhibits an exceedingly weak “insulating state”, with barely a 10 % rise in the resistance from 4 K to the lowest measured temperatures at $B > B_{cross}$ as shown in Fig. 1 (a). This is again very different from strongly disordered InO_x films that show an enhancement of the resistance upwards of $10^9 \Omega$ at similar magnetic fields at low temperatures [3, 18]. Like other weak disordered superconducting films, the DC data show an apparent trend towards saturation at low temperatures for fields above 3 Tesla. This saturation was confirmed in separate two-terminal measurements of this sample down to dilution fridge temperatures [28].

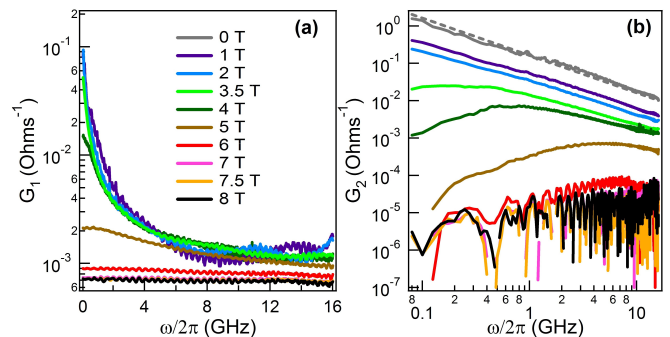


FIG. 2: (Color online) Frequency dependence of (a) real (G_1) and (b) imaginary (G_2) conductance respectively in the ranges $\omega/2\pi = 0.08 - 16$ GHz. G_1 and G_2 have the same color legend at finite fields except that G_1 at zero field is not plotted. The dashed grey line in (b) is a guide to the eye of $G_2 \propto 1/\omega$.

In Figs. 2 (a) and (b), we plot the real (G_1) and imaginary (G_2) conductance respectively as a function of frequency at the base temperatures for each field (≈ 426 mK for 5 Tesla and ≈ 300 mK for all other fields) [25, 29]. As shown by the straight line with a slope of -1 on the log-log plot in 2 (b), at zero field and 300 mK, G_2 shows the $1/\omega$ frequency dependence expected for a superconductor at frequencies below the gap. This dependence is consistent with $G_1 = \delta(\omega)$ *via* the Kramers-Kronig relation. Indeed, G_1 at zero field is small with a value that is at the limit of our experimental sensitivity, thus is not plotted. At $B \ll B_{cross}$, G_2 remains linear with

the same slope in the log-log plot but its magnitude drops dramatically as the field is increased. This implies that the δ -function in G_1 is preserved, although its spectral weight (proportional to the superfluid density) is greatly decreasing.

At intermediate field strengths ($B \sim 3$ Tesla), a maximum in G_2 appears. According to the Kramers-Kronig relation, this implies that a significant spectral component in G_1 has a finite width. As shown previously [24], the frequency of the maximum in G_2 corresponds to the characteristic fluctuation rate Ω in a fluctuating superconductor. The decrease in the frequency of the peak in G_2 as the field is reduced is an unambiguous signature of critical slowing down of the fluctuation frequency while approaching a transition. However, the peak in G_2 is developed at a field that is well below B_{cross} and the fluctuations are clearly *speeding up* as we approach B_{cross} from below. This behavior is inconsistent with the conventional wisdom for QCP phenomenologies if B_{cross} is a QCP because one generally expects a *slowing down* of the internal fluctuation frequency scales as one approaches a continuous transition. When $B \simeq B_{cross}$, we cannot distinguish the superconducting signal from the normal state background as G_1 is flat and featureless and G_2 is small. The data is reminiscent of what one expects for a disordered metal with a high scattering rate [24].

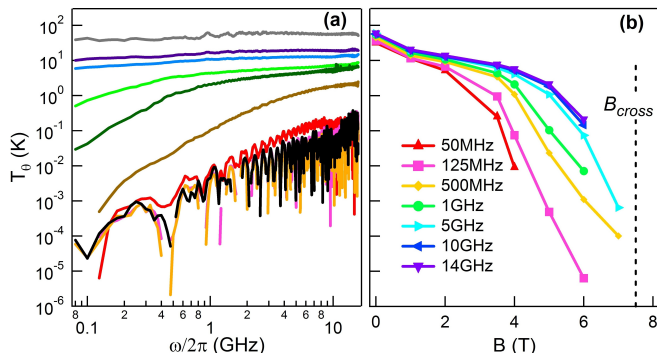


FIG. 3: (Color online) (a) Frequency dependence of the phase stiffness in the ranges $\omega/2\pi = 0.08 - 16$ GHz at the base temperature for each field. The color legend for fields is the same as in Fig. 2 (a). (b) Phase stiffness as a function of field at different frequencies at the base temperature for each field.

An essential quantity for analyzing superconducting fluctuations is the phase stiffness T_θ , which is the energy scale required to twist the phase of the superconducting order parameter. Within a parabolic band approximation, $T_\theta \propto N$, the superfluid density. More precisely (and in a model independent fashion), it is proportional to the spectral weight in the zero frequency delta function and can be measured through G_2 as $T_\theta(\omega) = \frac{G_2(\omega)}{G_Q} \frac{\hbar\omega}{k_B}$, where $G_Q = 1/R_Q$. This relation expresses the energy scale T_θ in degrees Kelvin, and gives the phase stiffness on a length scale set by the probing frequency. Fig. 3

(a) shows $T_\theta(\omega)$ at the respective base temperatures described above for each field. At low field, T_θ shows essentially no frequency dependence, which suggests that the phase is ordered on all lengths. We see a dramatic drop in T_θ at $B \ll B_{cross}$. For intermediate fields, T_θ starts to acquire a strong frequency dependence at low ω , which reflects that Cooper pairs have short-range correlations that can be resolved at high probing frequency while the long-range correlations are suppressed. At high ω the frequency dependence becomes less pronounced showing that one approaches a well-defined high frequency limit.

The rapid decrease in the overall scale of T_θ can be clearly observed in Fig. 3 (b) where we display field dependence of T_θ at several frequencies cuts from Fig. 3 (a). Above 2 Tesla, the curves start to spread, indicating the superconducting correlations gain a length dependence. At the lowest frequency (50 MHz, which probes the longest length scale), T_θ drops dramatically around 3 Tesla indicating that long range ordered phase coherence is suppressed by increasing fields. Note the strong suppression in T_θ in this field range; at some frequencies the suppression in T_θ can be followed over 7 orders of magnitude. Unlike the low frequency behavior, T_θ at high frequency extrapolates towards zero near B_{cross} . This latter finding greatly differs from previous microwave cavity measurements on a much more disordered InO_x film ($B_{cross} = 3.68$ Tesla) [4]. In that work the finite-frequency T_θ was non-zero well past the phenomenologically defined B_{cross} into the strongly insulating phase. This was interpreted as a state that while strongly insulating on long length scales, has superconducting correlations on short ones. In contrast, T_θ for our low-disorder film vanishes on approaching B_{cross} instead of staying finite well beyond it. This indicates that the superconducting correlations do not survive appreciably through B_{cross} and the superfluid density is indistinguishable from zero into the weakly insulating state at the lowest temperatures we can access.

To form a more quantitative understanding of the fluctuations, we fit G_1 and G_2 to a model where the fluctuation contribution is given by a zero-frequency Lorentzian lineshape [30]. This is simpler, but essentially equivalent to the scaling analysis we performed previously to obtain the characteristic fluctuation rate approaching a finite temperature transition at zero field [24]. Lorentzian fits are equivalent to assuming that time correlations are exponentially diverging while approaching the transition. The fits agree well with the data (see the SI), thus justifying this assumption. In this model the fitted width of G_1 is the characteristic fluctuation rate $\Omega(T)$, while its integrated area is equivalent to the high frequency limit of T_θ (in appropriate units).

In Fig. 4 (a), we plot $\Omega(T)$ for fields up to 6 Tesla. Data above 6 Tesla exhibit fluctuation rates that are far above our accessible frequency range. At zero field, Ω goes to zero when T approaches T_c from above showing

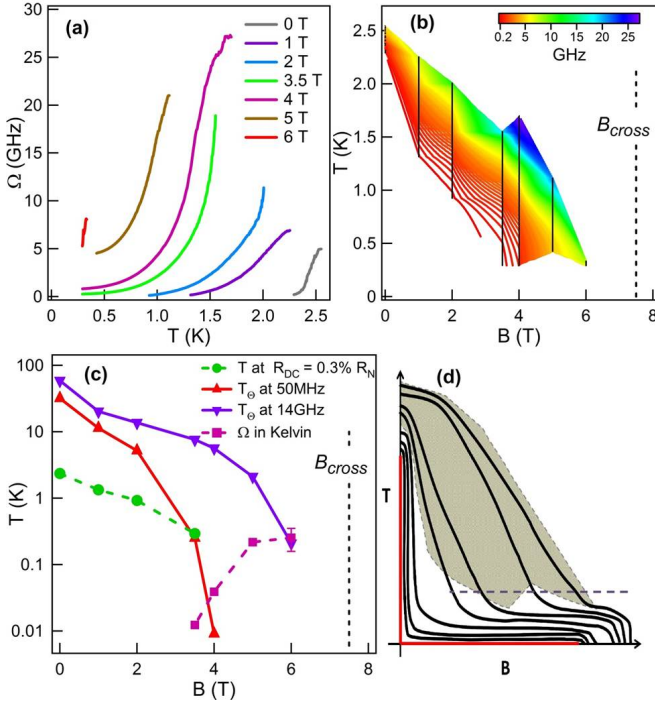


FIG. 4: (Color online) (a) Temperature dependence of Ω at different magnetic fields. (b) Contour plot of Ω in temperature and field. Solid vertical black lines are the actual B and T values where data were taken. Color indicates the magnitude of interpolated values of Ω from the fitted data. (c) A phase diagram of all the quantities converted to unit of Kelvin. The dashed vertical black lines in (b) and (c) mark B_{cross} . (d) An alternative scenario for contour plot of Ω assuming B_{cross} is the QCP.

the critical slowing down that confirms our previous results [24]. Ω drops in a much slower fashion at finite fields and even begins to saturate to a finite value at the lowest temperatures for $B \gtrsim 2$ Tesla. Fig. 4 (b) is a contour plot of Ω in field and temperature. It is safe to conclude that the $\Omega = 0$ contour falls below the lowermost curve that has $\Omega = 0.2$ GHz. In general, small Ω contours at low temperatures extrapolate to zero at a field less than 3 Tesla, which is again far below B_{cross} .

To form a global view, we bring a number of these quantities together in a single phase diagram in Fig. 4 (c). For all quantities, energy scales and frequencies have been converted to energy units (in degrees Kelvin). Upward and downward triangles show the low and high frequency limits of T_θ in our setup's accessible frequency range. Squares are $\Omega(T)$ taken at base temperatures. Circles demonstrate the temperature when $R_\square = 0.3\% R_N$, where R_N is the sheet resistance at 4 K. It denotes a region in phase space where the resistance is “small”. It is clear from this plot that T_θ in the zero-frequency limit and Ω converge towards zero at $B \approx 3$ Tesla. This “V” shaped phase diagram is exactly what one expects

near a QCP where energy scales extrapolate to zero from either side. Again, B_{cross} , which is conventionally considered to be a QCP, appears to be completely unrelated to the actual critical behavior. One can see that B_{cross} is the field scale where the high frequency T_θ is suppressed. Due to the lack of evidence for a diverging $R_\square$ at $B_{sm} < B < B_{cross}$ in the zero-temperature limit, one reasonable interpretation of the phase diagram is that this low-disorder InO_x film has a true QCP located at $B_{sm} \approx 3$ Tesla between a superconducting and an anomalous metallic state. In this picture B_{cross} only marks a crossover in behaviors between a dissipative state with strong superconducting correlations on short length scales and one with vanishing such correlations.

The view that B_{sm} instead of B_{cross} is the true QCP in *weakly* disordered films runs counter to much prevailing dogma in the field. If one is to insist that B_{cross} controls the critical behavior, it requires at least two additional conditions to explain our data, both of which we consider unlikely. First, one has to posit that the contours of constant Ω must have particular shapes like those shown in Fig. 4 (d) and what we are seeing is a finite temperature effect. If, as discussed above, a true superconducting state only exists for $T \neq 0$, $B = 0$ and $T = 0$, $B \neq 0$, the true $\Omega = 0$ contours are the two red lines lying on the $B = 0$ and $T = 0$ axes. All the finite Ω contours should intercept the two axes at $T > T_c$, $B = 0$ or $B > B_{cross}$, $T = 0$. In our case, this means that these contours would have to have exceedingly long tails extending over B_{cross} . Although we cannot exclude this possibility, it is a challenge within the current theoretical framework to explain why the contours would pick up this particular shape. Secondly, if B_{cross} is the actual QCP, the AC dynamics must be completely insensitive to the existence of the QCP as we have seen no evidence of quantum critical signatures in our AC data extrapolating towards B_{cross} . This may be possible, but only in a scenario where the QPT is a transition associated with pure classical percolation [16, 31].

To conclude, we find evidence for a possible scenario where a 2D QPT occurs at a field B_{sm} between a superconductor and an anomalous metal with superconducting correlations. The lowest temperature Ω and T_θ at the lowest frequency extrapolate to zero from both sides of B_{sm} . The lack of evidence for finite-frequency T_θ surviving B_{cross} shows that B_{cross} is a crossover above which superconducting fluctuations make a vanishing contribution to both DC transport and AC measurements. A careful and complete investigation of a more disordered film is needed to compare the affects of different disorder levels, which is a future direction of our project.

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- [25] The sample at 5 Tesla had a impedance closely matched to the cable thus had a maximum absorption of microwave radiations. The lowest temperature for that field was 426 mK under microwave radiation. The heating effects at other fields were negligible.
- [26] The contribution of the Si substrate to the sample impedance is obtained by comparing the measured zero-field AC signal of the InO_x/substrate system in the normal state with the normal-state frequency independent InO_x film impedance value. See Ref. [20, 24] for more detailed information.
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- [28] Unfortunately, a direct comparison between the two DC data sets cannot be made as the InO_x sample anneals even at room temperature over the course of the intervening months. As shown in the supplementary information, although the sample changed with a systematic movement of curves with the same resistance to higher fields, the data sets are overall very similar with continuing trend towards saturation at low temperatures.
- [29] Due to a missing set of calibration curves, the data at 4 Tesla were calibrated using an effective calibration interpolated from 3.5 Tesla and 5 Tesla calibration standards. We estimate that the error introduced by this interpolation is less than 1 %.
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Supplementary information

A separate measurement of the same sample down to 60 mK was carried out roughly half a year after the microwave measurements. The sample has been kept in the dry box the whole time and has lost some oxygen over the course of intervening months. In Fig. 5 (a), we display $R_{\square}$ as a function of temperature at different fields. The level of disorder has changed with a new $T_c \cong 2.68$ K at zero field. We show $R_{\square}$ as a function of field at 75 mK and 150 mK in Fig. 5 (b) and one can clearly see that B_{cross} changes to 7.86 Tesla.

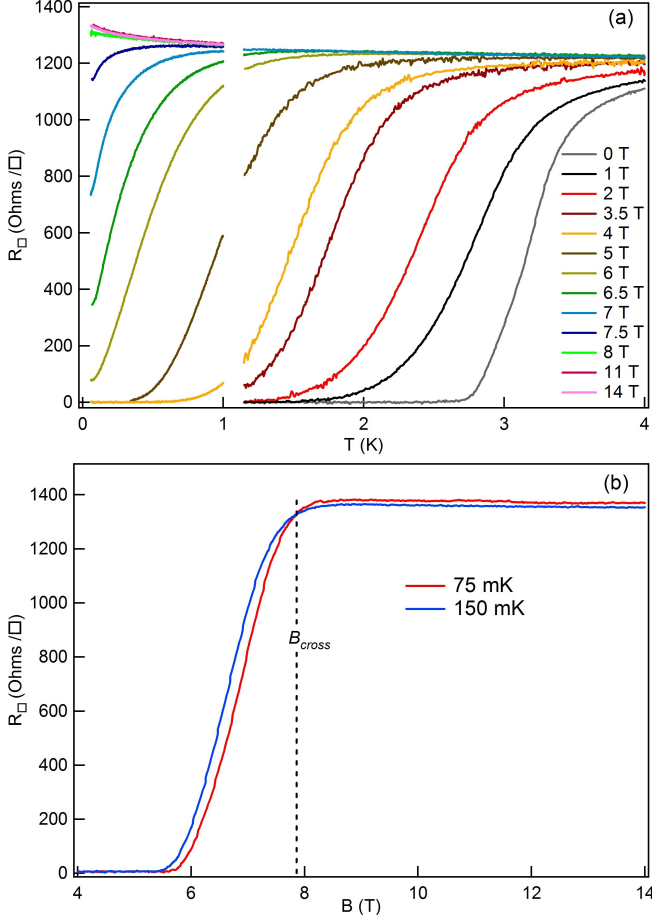


FIG. 5: (a) Temperature dependence of the $R_{\square}$ measured in the range $T = 0.06 - 4$ K at fields represented by the color legend. (b) $R_{\square}$ as a function of field at two fixed low temperatures.

As we discussed in the main text, we fit G_1 and G_2 to a Lorentzian lineshape,

$$G = \sigma d = \frac{N_1 e^2 d \tau_1}{m} \frac{1}{1 - i\omega\tau_1} + \frac{N_2 e^2 d \tau_2}{m} \frac{1}{1 - i\omega\tau_2} \quad (1)$$

Essentially, we use two Drude models to describe the combined contributions from the normal electrons and superconducting fluctuations to the complex conductance. The scattering rates of the normal electrons for this film are much bigger than Ω and exceed our frequency range. Therefore, the Drude term of the normal electrons just makes a constant contribution to G_1 and a negligible contribution to G_2 . In Fig. 6, we show the fitting to G_1 and G_2 at $B = 3.5$ Tesla, $T = 850$ mK as an example and the fitting agrees well with our experimental data. For this particular data set, the complex

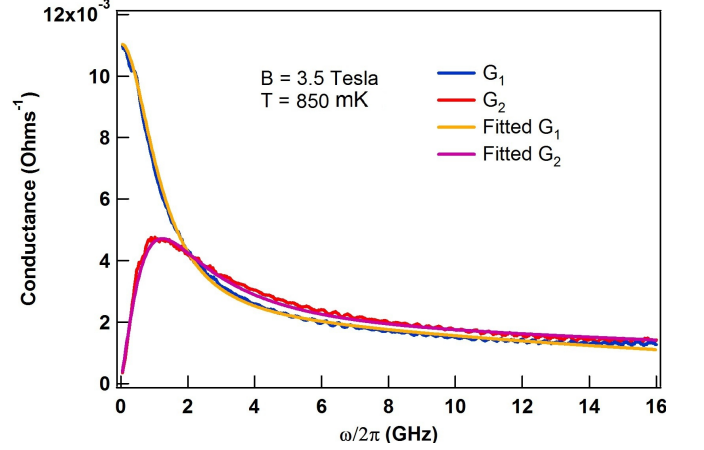


FIG. 6: Experiment measured G_1 and G_2 and fitted data to a Lorentzian lineshape model.

conductance can be fitted as,

$$G = 0.0094 * \frac{1}{1 - i\omega/(2\pi * 1.239)GHz} + 0.00172 * \frac{1}{1 - i\omega/(2\pi * 22.787)GHz}$$